



GaN FET Technology 200 Watt Series

Small Size Desktop Type



Features:

■ IEC/EN/ANSI/AAMI ES60601-1 (Edition 3.1)

■ IEC/EN/ANSI/AAMI HA60601-1-11 (Class II Only)

■ EMC : IEC60601-1-2 : 2014 (Edition 4.0)

■ 100-240 VAC Universal Input

■ Gallium Nitride Based Design

■ High Power Density: 11W / in³

■ With 250kHz Switching Frequency

■ Means of Protection: 2 X MOPP

■ Touch Current : < 100µA

■ Efficiency up to 95%

■ Regulated Output with Low Ripple Noise

■ Modified and Custom Design Available

■ 2 Years Warranty

Model	O/P Voltage	O/P Current	Watt
ATM200TS-□120	12.0V	16.0A	192W
ATM200TS-□150	15.0V	13.0A	195W
ATM200TS-□190	19.0V	10.5A	200W
ATM200TS-□240	24.0V	8.3A	200W
ATM200TS-□480	48.0V	4.2A	200W

Input	
Voltage	100-240VAC
Line Frequency	50-60Hz
Current	2.4-0.9A
Protection	Internal Primary Current Fuse
Configuration	IEC60320/C6, C8, C14, C18

Output	
Load Regulation	±5% (Typical)
Ripple & Noise	1% Vp-p Max. for Output Voltage @ Full Load
Transient Response	0.5mS for 50% Load Change Typical
Hold-up Time	10mS @ Full Load
Protection	Short Circuit Protection / Over Voltage Protection / Over Current Protection / Over Temperature Protection

Electrical		
Topology	LLC	
Dielectric Withstand	4000VAC Primary - Secondary	
Touch Current	< 100µA	
Efficiency	DoE Level VI, ErP Stage 2, CoC Tier 2	
EMC Standards	EN55011	
	EN61000-3-2,3	
	EN61000-4-2,3,4,5,6,8,11	
MTBF	300,000 Calculated Hours at 25°C , by Telcordia SR-332	

Environmental		
Operating Temperature	-20 to + 40°C	
Storage Temperature	-20 to + 80°C	
Relative Humidity	Operating: 20 to 80% RH	
	Storage: 10 to 90% RH	
Cooling	Natural Convection Cooling	

Mechanical	
Case Dimension	L 166.5 × W 54.2 × H 33 (mm)
Weight	620g (Ref.)





